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**CENTRAL FAX CENTER****Patent****OCT 18 2006**Customer No.: 31561  
Application No.: 10/711,478  
Docket No. : 13530-US-PA**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Applicant : His-Ming Chang

Application No. : 10/711,473

Filed : September 21, 2004

For : LOW TEMPERATURE POLYSILICON THIN FILM  
TRANSISTOR AND METHOD OF FABRICATING  
LIGHTLY DOPED DRAIN THEREOF

Art Unit : 2826

Examiner : ERDEM, FAZLI

**TRANSMITTAL LETTER****+1-571-273-8300****(Via fax: 1+2+11 pages)**ASSISTANT COMMISSIONER FOR PATENTS  
Alexandria, VA 22314

Dear Sir,

In response to the Final Office Action dated July 18, 2006, please find the relevant papers as follows:

- ☒ Request for Continued Examination in (2) pages;  
☒ Preliminary Amendment in (11) pages.

Thank you for your assistance in the subject matter. If you have any questions, please feel free to contact me.

Respectfully Submitted,  
JIANQ CHYUN Intellectual Property OfficeDate: Oct. 18, 2006By: Belinda Lee  
Belinda Lee  
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